# ESD Protection Diode Array

Low Capacitance ESD Protection Diode for High Speed Data Line

# **ESD1014**

The ESD1014 surge protectionis designed to protect high speed data lines from ESD, EFT, and lightning.

#### Features

- Low Capacitance (6 pF Maximum Between I/O Lines and GND)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body model and Class C (Exceeding 400 V) per Machine Model
- Protection for the Following IEC Standards: IEC 61000-4-2 (ESD) Level 4 - 30 kV (Contact)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a Pb–Free Device

#### **Typical Applications**

- High Speed Communication Line Protection
- USB 1.1 and 2.0 Power and Data Line Protection
- Digital Video Interface (DVI)
- Monitors and Flat Panel Displays
- T1/E1 and T3/E3
- 10/100/1000 Ethernet Protection
- Gigabit Ethernet Protection

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

| Rating  | Symbol           | Value           | Unit |
|---|------------------|-----------------|------|
| Peak Power Dissipation (Note 1)   | P <sub>pk</sub>  | 450             | W    |
| Maximum Peak Pulse Current<br>(Note 1)                                      | I <sub>PP</sub>  | 30              | A    |
| Operating Junction Temperature Range  | TJ               | -40 to +125     | °C   |
| Storage Temperature Range   | T <sub>stg</sub> | –55 to +150     | °C   |
| Lead Solder Temperature –<br>Maximum (10 Seconds)                           | ΤL               | 260             | °C   |
| Machine Model (MM)<br>Human Body Model (HBM)<br>IEC 61000-4-2 Contact (ESD) | ESD              | 0.4<br>16<br>30 | kV   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. 8/20  $\mu$ s Waveform per Figure 2 (@ T<sub>A</sub> = 25°C).

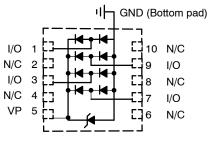


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### LOW CAPACITANCE DIODE SURGE PROTECTION ARRAY

#### **PIN CONFIGURATION** AND SCHEMATIC





# MARKING DIAGRAM

UDFN10



CASE 517AN

| 1014<br>A | = Specific Device Code<br>= Assembly Location |
|-----------|---|
| Y         | = Year  |
| W         | = Work Week                                   |
| •         | = Pb-Free Package                             |

#### **ORDERING INFORMATION**

| Device         | Package             | Shipping <sup>†</sup> |
|----------------|---------------------|-----------------------|
| ESD1014MUTAG   | UDFN10<br>(Pb-Free) | 3000 / Tape &<br>Reel |
| SZESD1014MUTAG | UDFN10<br>(Pb-Free) | 3000 / Tape &<br>Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## ESD1014

| Parameter                  | Symbol           | Conditions  | Min | Тур | Max              | Unit |
|----------------------------|------------------|---|-----|-----|------------------|------|
| Reverse Working Voltage    | V <sub>RWM</sub> | (Note 1)  |     |     | 3.3              | V    |
| Breakdown Voltage          | V <sub>BR</sub>  | I <sub>T</sub> =1 mA, (Note 2)                              | 5.0 | 5.3 |                  | V    |
| Reverse Leakage Current    | I <sub>R</sub>   | V <sub>RWM</sub> = 3.3 V                                    |     |     | 5.0              | μA   |
| Clamping Voltage           | V <sub>C</sub>   | Pin 5 to GND, I <sub>PP</sub> = 1 A                         |     |     | 6.2              | V    |
| Clamping Voltage           | V <sub>C</sub>   | Any I/O pin to GND<br>Ipp = 1 A<br>Ipp = 10 A<br>Ipp = 25 A |     |     | 7.5<br>9.0<br>11 | V    |
| Maximum Peak Pulse Current | I <sub>PP</sub>  | 8/20 μs Waveform per Figure 2                               |     |     | 30               | А    |
| Junction Capacitance C     | CJ               | $V_R = 0 V$ , f=1 MHz between I/O Pins and GND              |     | 3.8 | 5.0              | pF   |
|                            |                  | V <sub>R</sub> = 0 V, f=1 MHz between I/O Pins              |     | 1.5 | 3.0              | 1    |

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise specified)

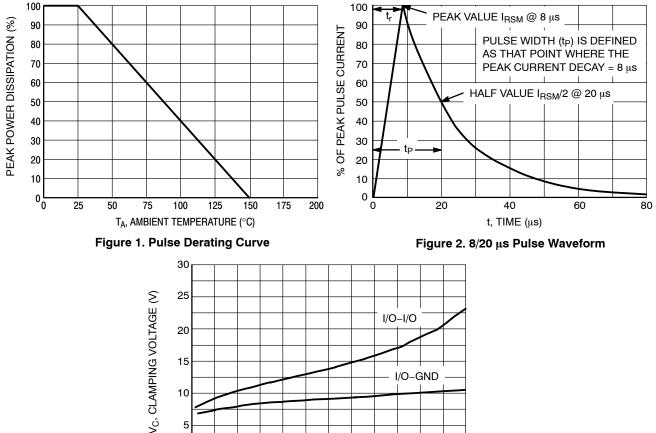
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

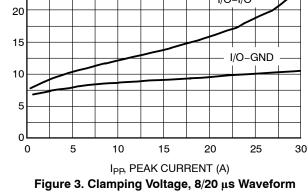
Surge protection devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater 1. than the DC or continuous peak operating voltage level.

2. V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.

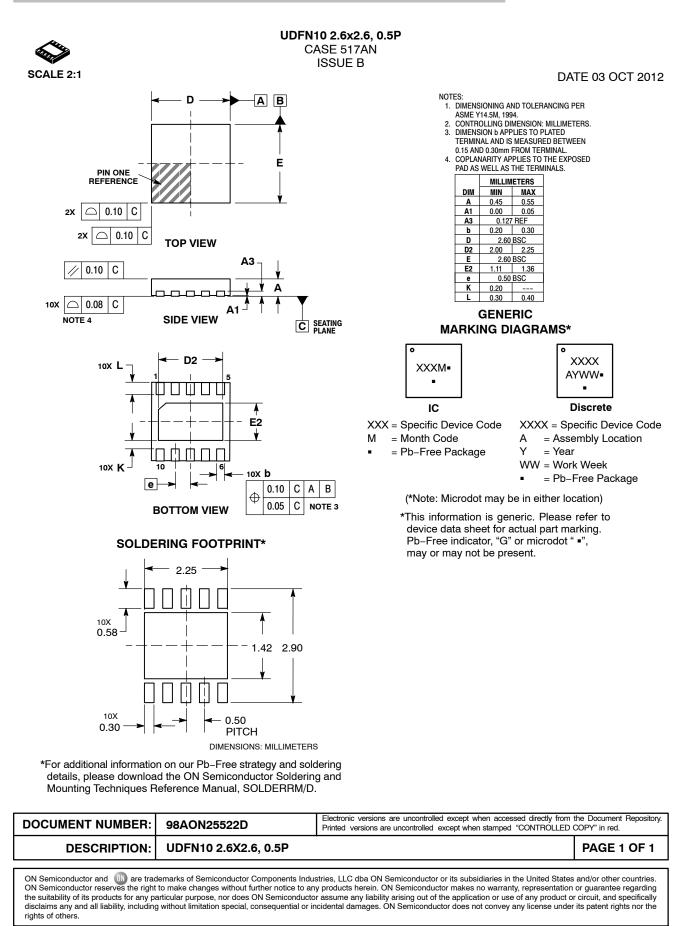
#### **TYPICAL PERFORMANCE CURVES**

(T<sub>1</sub> = 25°C unless otherwise noted)









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